

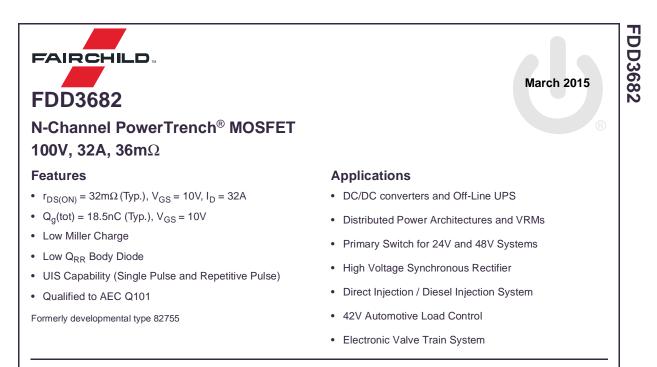
Is Now Part of



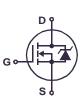
# **ON Semiconductor**®

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# MOSFET Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V <sub>DSS</sub>	Drain to Source Voltage	100	V	
V <sub>GS</sub>	Gate to Source Voltage	±20	V	
I <sub>D</sub>	Drain Current			
	Continuous (T <sub>C</sub> = $25^{\circ}$ C, V <sub>GS</sub> = 10V)	32	A	
	Continuous ( $T_C = 100^{\circ}C$ , $V_{GS} = 10V$ )	23	A	
	Continuous ( $T_{amb} = 25^{\circ}C$ , $V_{GS} = 10V$ , $R_{\theta JA} = 52^{\circ}C/W$ )	5.5	A	
	Pulsed	Figure 4	A	
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 1)	55	mJ	
P <sub>D</sub>	Power dissipation	95	W	
	Derate above 25°C	0.63	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature	-55 to 175	°C	

# **Thermal Characteristics**

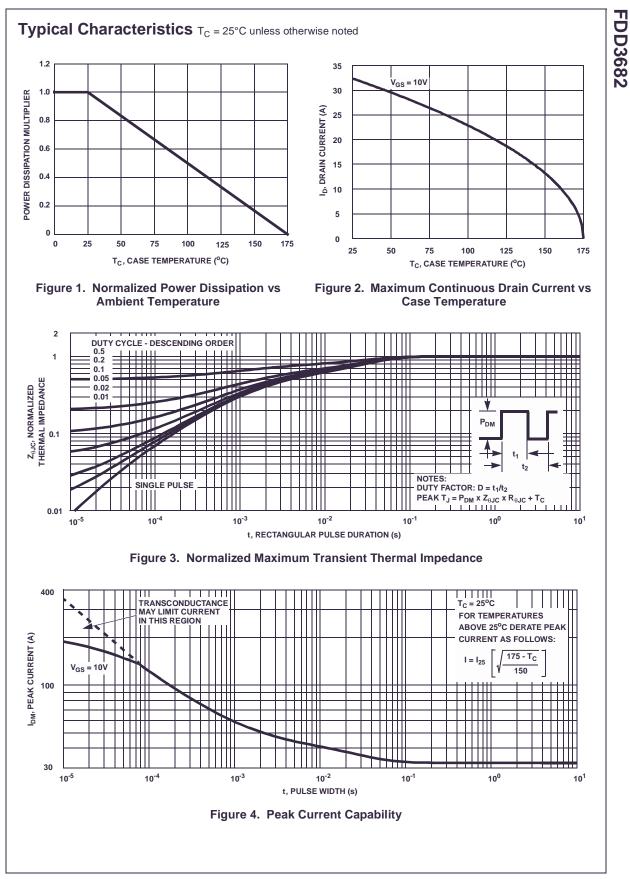
$R_{ extsf{ heta}JC}$	Thermal Resistance Junction to Case TO-252	1.58	°C/W
$R_{\thetaJA}$	Thermal Resistance Junction to Ambient TO-252	100	°C/W
$R_{\thetaJA}$	Thermal Resistance Junction to Ambient TO-252, 1in <sup>2</sup> copper pad area	52	°C/W

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/

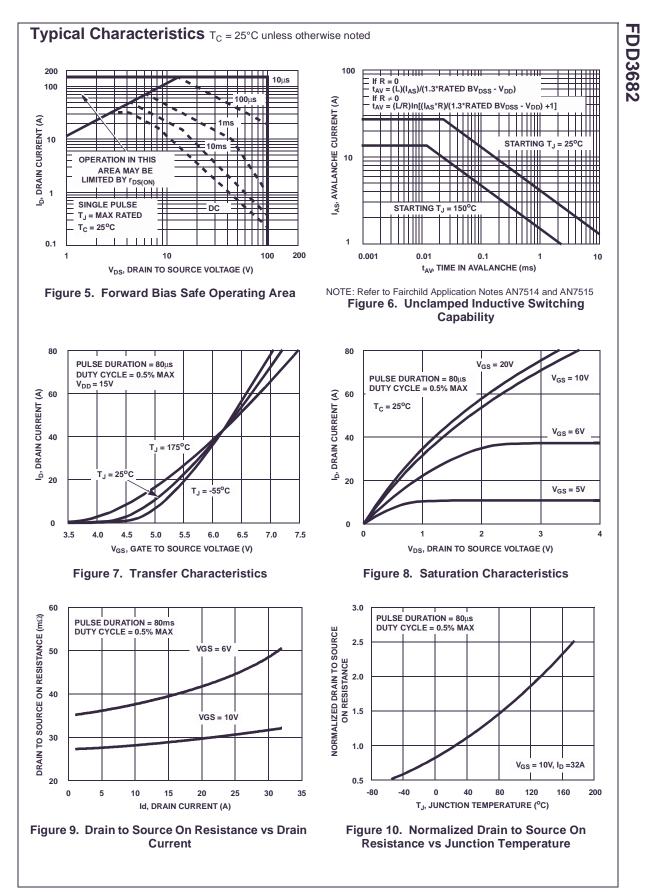
Reliability data can be found at: http://www.fairchildsemi.com/products/discrete/reliability/index.html.

All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

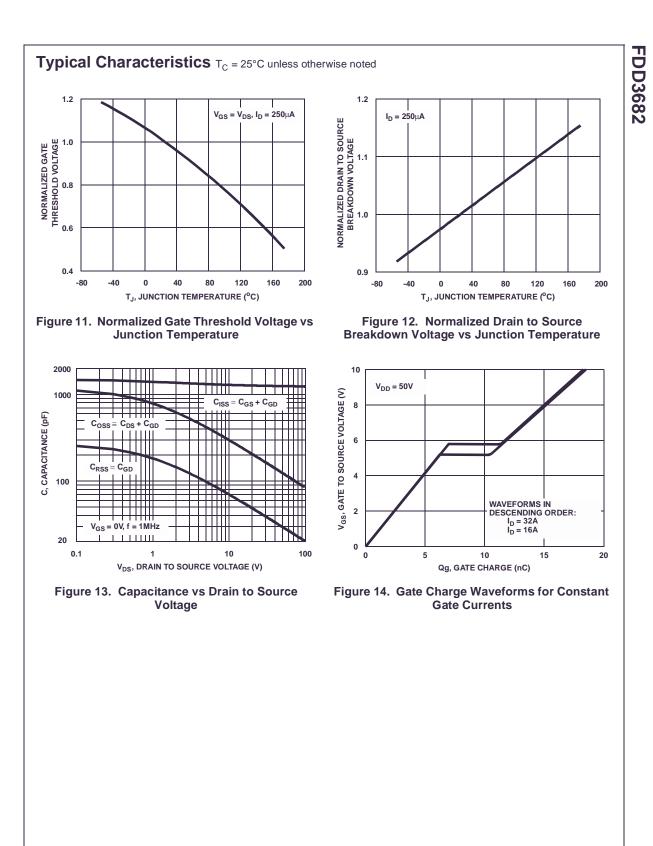
Device N	Device MarkingDeviceFDD3682FDD3682		Package	Reel Size	Таре	Width	Qua	ntity	
FDD3			TO-252AA	330mm	16	nm	2500 units		
	al Chara		1						
Symbol		Parameter	Test	Conditions	Min	Тур	Max	Units	
off Chara	cteristics	S							
B <sub>VDSS</sub>	Drain to S	ource Breakdown Voltage	I <sub>D</sub> = 250μA	, V <sub>GS</sub> = 0V	100	-	-	V	
I <sub>DSS</sub>			$V_{DS} = 80V$		-	-	1	μA	
088	Zero Gate Voltage Drain Current		$V_{GS} = 0V$	$T_{C} = 150^{\circ}C$	-	-	250	μι	
GSS	Gate to S	ource Leakage Current	$V_{GS} = \pm 20$	/	-	-	±100	nA	
)n Chara	cteristics	6							
V <sub>GS(TH)</sub>	-	ource Threshold Voltage	$V_{GS} = V_{DS}$	, I <sub>D</sub> = 250μA	2	-	4	V	
00(11)			I <sub>D</sub> = 32A, V		-	0.032	0.036		
	Drain to S	Cource On Posistones	I <sub>D</sub> = 16A, V		-	0.040	0.060	0	
DS(ON)	Drain to Source On Resistance		I <sub>D</sub> = 32A, V T <sub>C</sub> = 175°C		-	0.080	0.090	Ω 00	
)vnamic	Characte	pristics			1	1	1		
C <sub>ISS</sub>	Input Cap				-	1250	-	pF	
C <sub>OSS</sub>			$V_{DS} = 25V, V_{GS} = 0V,$		-	190	-	pF	
RSS	-	Output Capacitance Reverse Transfer Capacitance		f = 1MHz		45	-	pF	
Q <sub>g(TOT)</sub>		otal Gate Charge at 10V		o 10V	-	18.5	28	nC	
λ <sub>g(TH)</sub>	-	I Gate Charge		$v_{DD} = 50V$	-	2.4	3.6	nC	
2 <sub>gs</sub>		ource Gate Charge		$I_D = 32A$	-	6.5	-	nC	
gs2	Gate Charge Threshold to Plateau		$I_g = 1.0$ mA		-	4.1	-	nC	
2 <sub>gd</sub>	Gate to Drain "Miller" Charge			-	-	4.6	-	nC	
	Switchin	ng Characteristics (V	10\/)						
	Turn-On T	-	GS = 10V		i	1	83	ns	
ON	_	On Time On Delay Time			-	9	05	ns	
d(ON)	Rise Time	,	 	V <sub>DD</sub> = 50V, I <sub>D</sub> = 32A		46	_	ns	
r	Turn-Off Delay Time			$R_{GS} = 16\Omega$	_	24	_	ns	
d(OFF)	Fall Time		63	63	-	26	-	ns	
	Turn-Off T	ime			-	-	75	ns	
rain-Sou	1	le Characteristics				-	75	115	
Var	Source to Drain Diode Voltage		I <sub>SD</sub> = 32A		-	-	1.25	V	
V <sub>SD</sub>			I <sub>SD</sub> = 16A		-	-	1.0	V	
rr		Recovery Time	-	dl <sub>SD</sub> /dt = 100A/µs	-	-	55	ns	
	Reverse F	Recovery Charge	$I_{SD} = 32A$ ,	dI <sub>SD</sub> /dt = 100A/µs	-	-	92	nC	



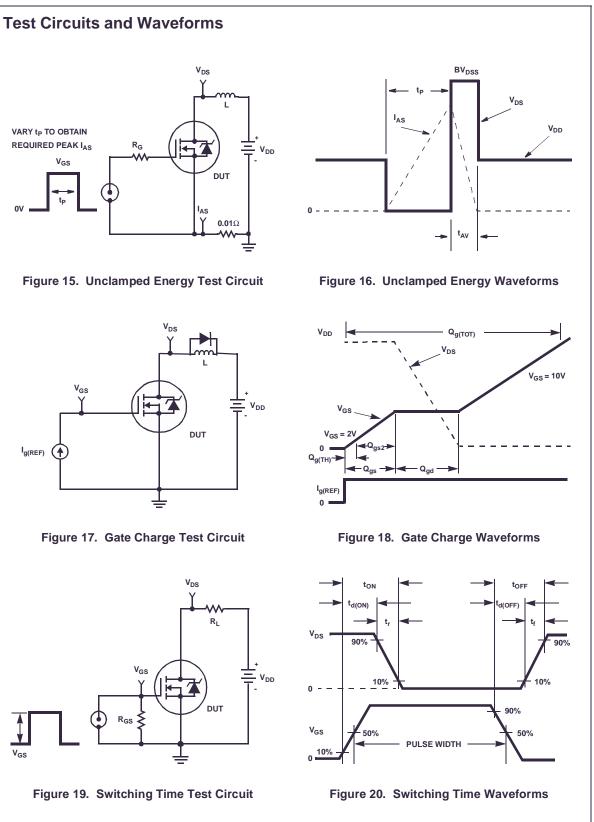
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FDD3682 Rev. 1.2



# FDD3682

V<sub>GS</sub>

I<sub>g(REF)</sub>

# FDD3682

# Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature,  $T_{JM}$ , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation,  $P_{DM}$ , in an application. Therefore the application's ambient temperature,  $T_A$  (°C), and thermal resistance  $R_{\theta JA}$  (°C/W) must be reviewed to ensure that  $T_{JM}$  is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-252 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of  $P_{DM}$  is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the  $R_{\theta,JA}$  for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 1oz copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

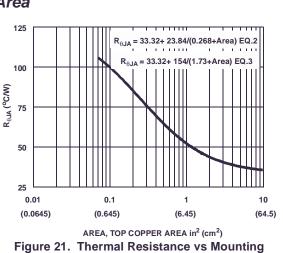
Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeter square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

$$R_{\theta JA} = 33.32 + \frac{23.84}{(0.268 + Area)}$$
(EQ. 2)

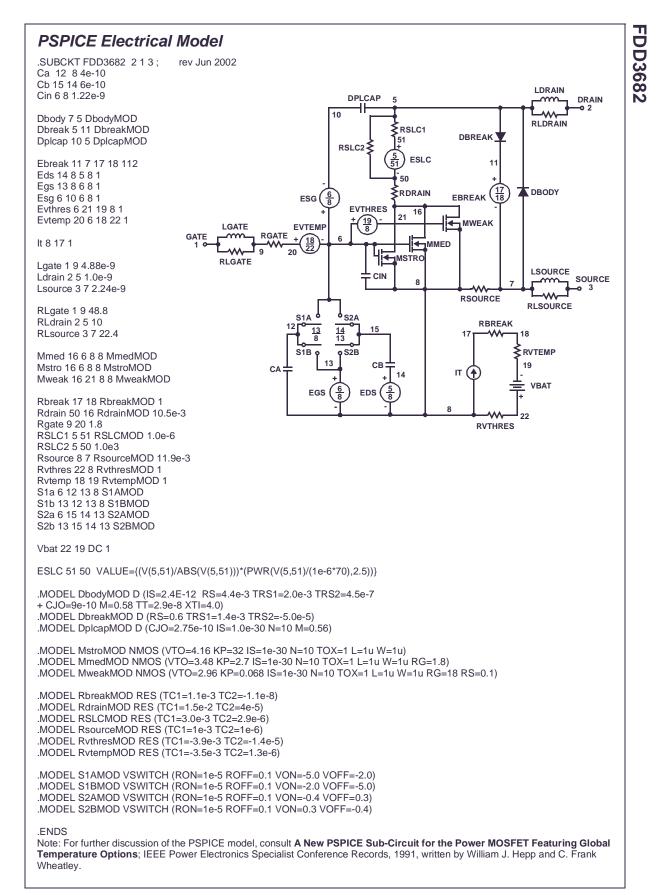
Area in Inches Squared

$$R_{\Theta JA} = 33.32 + \frac{154}{(1.73 + Area)}$$
 (EQ. 3)

Area in Centimeters Squared

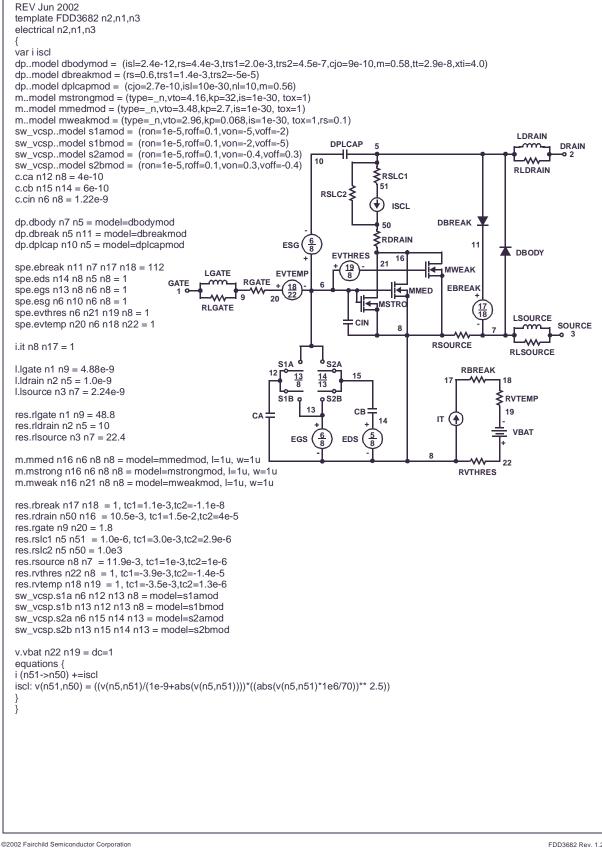


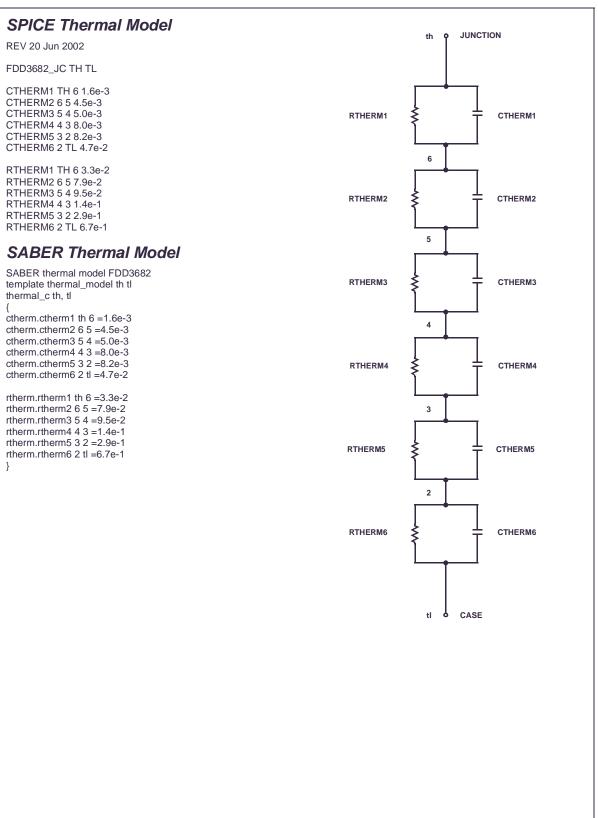




DD3682

# SABER Electrical Model





# FDD3682





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